

# SiT9121

## 1-220 MHz High Performance Differential Oscillator



### Features

- Any frequency between 1 MHz and 220 MHz accurate to 6 decimal places
- LVPECL and LVDS output signaling types
- 0.6ps RMS phase jitter (random) over 12 kHz to 20 MHz bandwidth
- Frequency stability as low as  $\pm 10$  ppm
- Industrial and extended commercial temperature ranges
- Industry-standard packages: 3.2x2.5, 5.0x3.2 and 7.0x5.0 mmxmm
- For frequencies higher than 220 MHz, refer to SiT9122 datasheet

### Applications

- 10GB Ethernet, SONET, SATA, SAS, Fibre Channel, PCI-Express
- Telecom, networking, instrumentation, storage, servers



INSTANT  
SAMPLES



GREEN  
SOLUTIONS



LIFETIME  
WARRANTY

### Electrical Characteristics

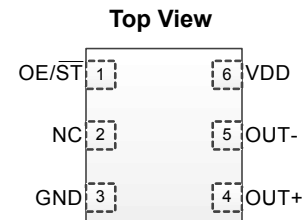
Parameter and Conditions	Symbol	Min.	Typ.	Max.	Unit	Condition
<b>LVPECL and LVDS, Common Electrical Characteristics</b>						
Supply Voltage	V <sub>dd</sub>	2.97	3.3	3.63	V	
		2.25	2.5	2.75	V	
		2.25	–	3.63	V	Termination schemes in Figures 1 and 2 - XX ordering code
		1.71	1.8	1.89	V	Only for LVDS output
Output Frequency Range	f	1	–	220	MHz	
Frequency Stability	F <sub>stab</sub>	-10	–	+10	ppm	Inclusive of initial tolerance, operating temperature, rated power supply voltage, and load variations
		-20	–	+20	ppm	
		-25	–	+25	ppm	
		-50	–	+50	ppm	
First Year Aging	F <sub>aging1</sub>	-2	–	+2	ppm	25°C
10-year Aging	F <sub>aging10</sub>	-5	–	+5	ppm	25°C
Operating Temperature Range	T <sub>use</sub>	-40	–	+85	°C	Industrial
		-20	–	+70	°C	Extended Commercial
Input Voltage High	V <sub>IH</sub>	70%	–	–	V <sub>dd</sub>	Pin 1, OE or $\overline{ST}$
Input Voltage Low	V <sub>IL</sub>	–	–	30%	V <sub>dd</sub>	Pin 1, OE or $\overline{ST}$
Input Pull-up Impedance	Z <sub>in</sub>	–	100	250	k $\Omega$	Pin 1, OE logic high or logic low, or $\overline{ST}$ logic high
		2	–	–	M $\Omega$	Pin 1, $\overline{ST}$ logic low
Start-up Time	T <sub>start</sub>	–	6	10	ms	Measured from the time V <sub>dd</sub> reaches its rated minimum value.
Resume Time	T <sub>resume</sub>	–	6	10	ms	In Standby mode, measured from the time $\overline{ST}$ pin crosses 50% threshold.
Duty Cycle	DC	45	–	55	%	Contact SiTime for tighter duty cycle
<b>LVPECL, DC and AC Characteristics</b>						
Current Consumption	I <sub>dd</sub>	–	61	69	mA	Excluding Load Termination Current, V <sub>dd</sub> = 3.3V or 2.5V
OE Disable Supply Current	I <sub>OE</sub>	–	–	35	mA	OE = Low
Output Disable Leakage Current	I <sub>leak</sub>	–	–	1	$\mu$ A	OE = Low
Standby Current	I <sub>std</sub>	–	–	100	$\mu$ A	$\overline{ST}$ = Low, for all V <sub>dds</sub>
Maximum Output Current	I <sub>driver</sub>	–	–	30	mA	Maximum average current drawn from OUT+ or OUT-
Output High Voltage	V <sub>OH</sub>	V <sub>dd</sub> -1.1	–	V <sub>dd</sub> -0.7	V	See Figure 1(a)
Output Low Voltage	V <sub>OL</sub>	V <sub>dd</sub> -1.9	–	V <sub>dd</sub> -1.5	V	See Figure 1(a)
Output Differential Voltage Swing	V <sub>Swing</sub>	1.2	1.6	2.0	V	See Figure 1(b)
Rise/Fall Time	T <sub>r</sub> , T <sub>f</sub>	–	300	700	ps	20% to 80%, see Figure 1(a)
OE Enable/Disable Time	T <sub>oe</sub>	–	–	115	ns	f = 212.5 MHz - For other frequencies, T <sub>oe</sub> = 100ns + 3 period
RMS Period Jitter	T <sub>jitt</sub>	–	1.2	1.7	ps	f = 100 MHz, V <sub>DD</sub> = 3.3V or 2.5V
		–	1.2	1.7	ps	f = 156.25 MHz, V <sub>DD</sub> = 3.3V or 2.5V
		–	1.2	1.7	ps	f = 212.5 MHz, V <sub>DD</sub> = 3.3V or 2.5V
RMS Phase Jitter (random)	T <sub>phj</sub>	–	0.6	0.85	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all V <sub>dds</sub>
<b>LVDS, DC and AC Characteristics</b>						
Current Consumption	I <sub>dd</sub>	–	47	55	mA	Excluding Load Termination Current, V <sub>dd</sub> = 3.3V or 2.5V
OE Disable Supply Current	I <sub>OE</sub>	–	–	35	mA	OE = Low
Differential Output Voltage	V <sub>OD</sub>	250	350	450	mV	See Figure 2

### Electrical Characteristics (continued)

Parameter and Conditions	Symbol	Min.	Typ.	Max.	Unit	Condition
<b>LVDS, DC and AC Characteristics (continued)</b>						
Output Disable Leakage Current	I <sub>leak</sub>	–	–	1	μA	OE = Low
Standby Current	I <sub>std</sub>	–	–	100	μA	$\overline{ST}$ = Low, for all V <sub>dds</sub>
VOD Magnitude Change	ΔVOD	–	–	50	mV	See Figure 2
Offset Voltage	VOS	1.125	1.2	1.375	V	See Figure 2
VOS Magnitude Change	ΔVOS	–	–	50	mV	See Figure 2
Rise/Fall Time	T <sub>r</sub> , T <sub>f</sub>	–	495	700	ps	20% to 80%, see Figure 2
OE Enable/Disable Time	T <sub>oe</sub>	–	–	115	ns	f = 212.5 MHz - For other frequencies, T <sub>oe</sub> = 100ns + 3 period
RMS Period Jitter	T <sub>jitt</sub>	–	1.2	1.7	ps	f = 100 MHz, VDD = 3.3V or 2.5V
		–	1.2	1.7	ps	f = 156.25 MHz, VDD = 3.3V or 2.5V
		–	1.2	1.7	ps	f = 212.5 MHz, VDD = 3.3V or 2.5V
RMS Phase Jitter (random)	T <sub>phj</sub>	–	0.6	0.85	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all V <sub>dds</sub>

### Pin Description

Pin	Map		Functionality
1	OE	Input	H or Open: specified frequency output L: output is high impedance
	$\overline{ST}$	Input	H or Open: specified frequency output L: Device goes to sleep mode. Supply current reduces to I <sub>std</sub> .
2	NC	NA	No Connect; Leave it floating or connect to GND for better heat dissipation
3	GND	Power	VDD Power Supply Ground
4	OUT+	Output	Oscillator output
5	OUT-	Output	Complementary oscillator output
6	VDD	Power	Power supply voltage



### Absolute Maximum

Attempted operation outside the absolute maximum ratings may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

Parameter	Min.	Max.	Unit
Storage Temperature	-65	150	°C
VDD	-0.5	4	V
Electrostatic Discharge (HBM)	–	2000	V
Soldering Temperature (follow standard Pb free soldering guidelines)	–	260	°C

### Thermal Consideration

Package	θJA, 4 Layer Board (°C/W)	θJC, Bottom (°C/W)
7050, 6-pin	142	27
5032, 6-pin	97	20
3225, 6-pin	109	20

### Environmental Compliance

Parameter	Condition/Test Method
Mechanical Shock	MIL-STD-883F, Method 2002
Mechanical Vibration	MIL-STD-883F, Method 2007
Temperature Cycle	JESD22, Method A104
Solderability	MIL-STD-883F, Method 2003
Moisture Sensitivity Level	MSL1 @ 260°C

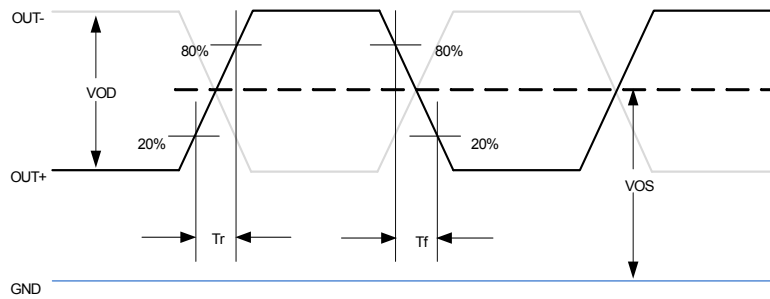
**Waveform Diagrams**



**Figure 1(a). LVPECL Voltage Levels per Differential Pin (OUT+/OUT-)**



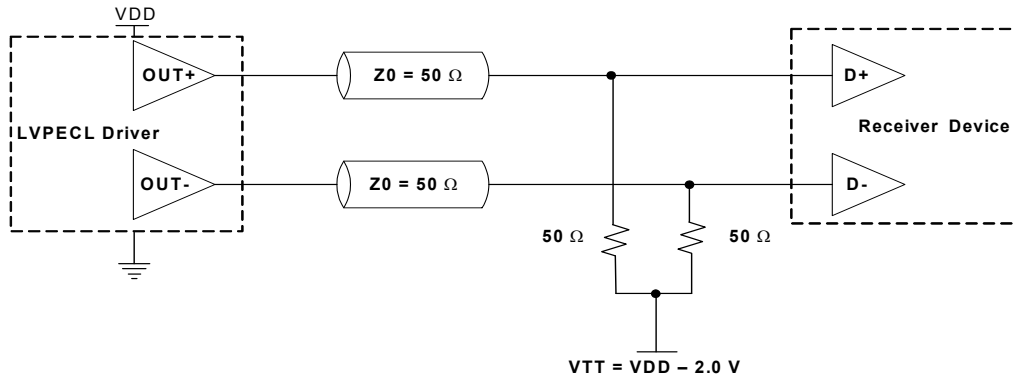
**Figure 1(b). LVPECL Voltage Levels Across Differential Pair**



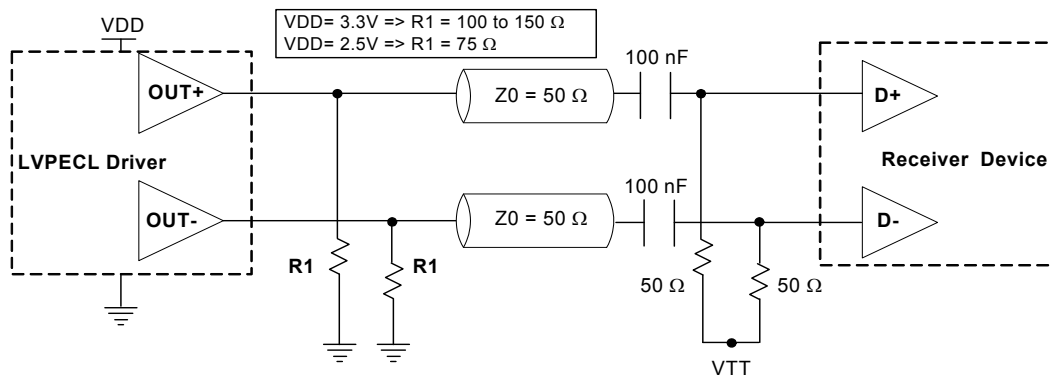
**Figure 2. LVDS Voltage Levels per Differential Pin (OUT+/OUT-)**

**Termination Diagrams**

LVPECL:



**Figure 3. LVPECL Typical Termination**



**Figure 4. LVPECL AC Coupled Termination**



**Figure 5. LVPECL with Thevenin Typical Termination**

LVDS:

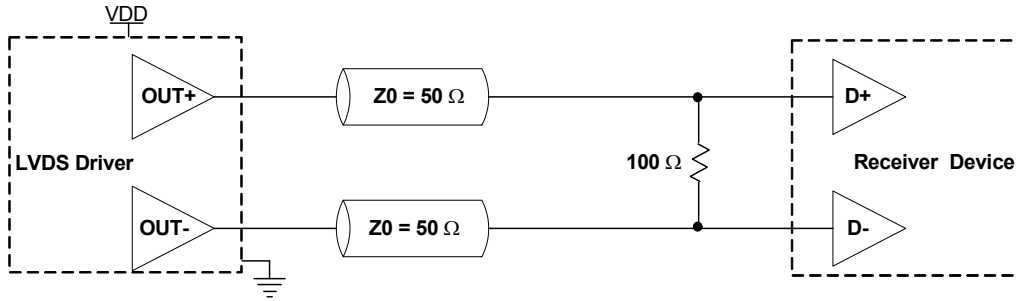
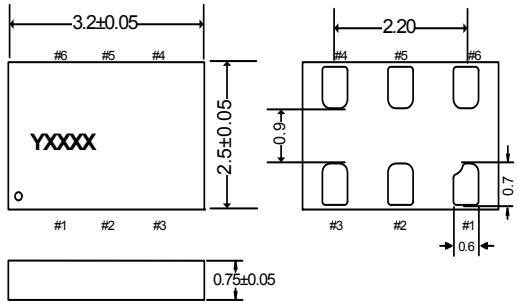
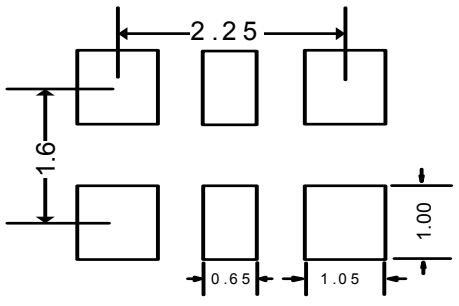
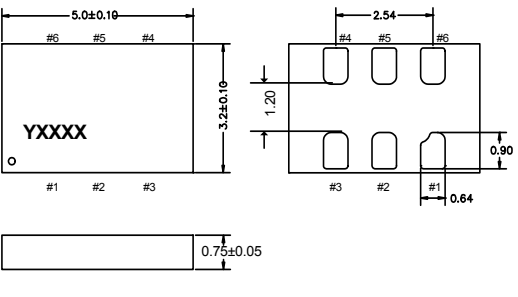
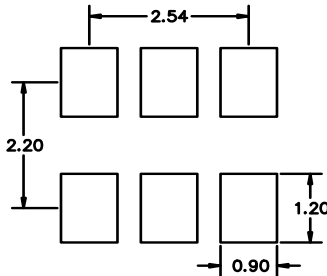
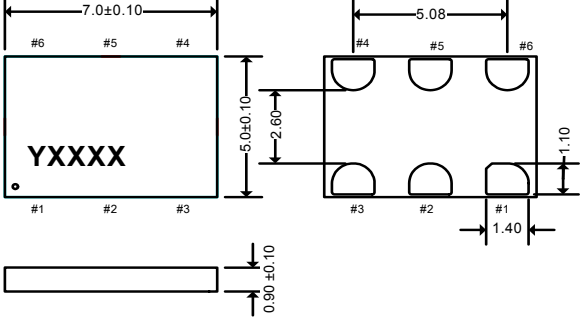
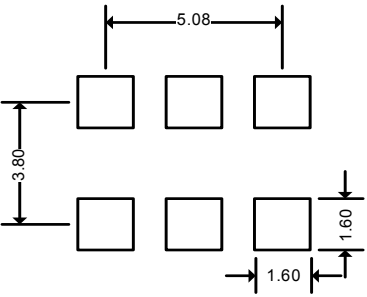


Figure 6. LVDS Single Termination (Load Terminated)

### Dimensions and Patterns

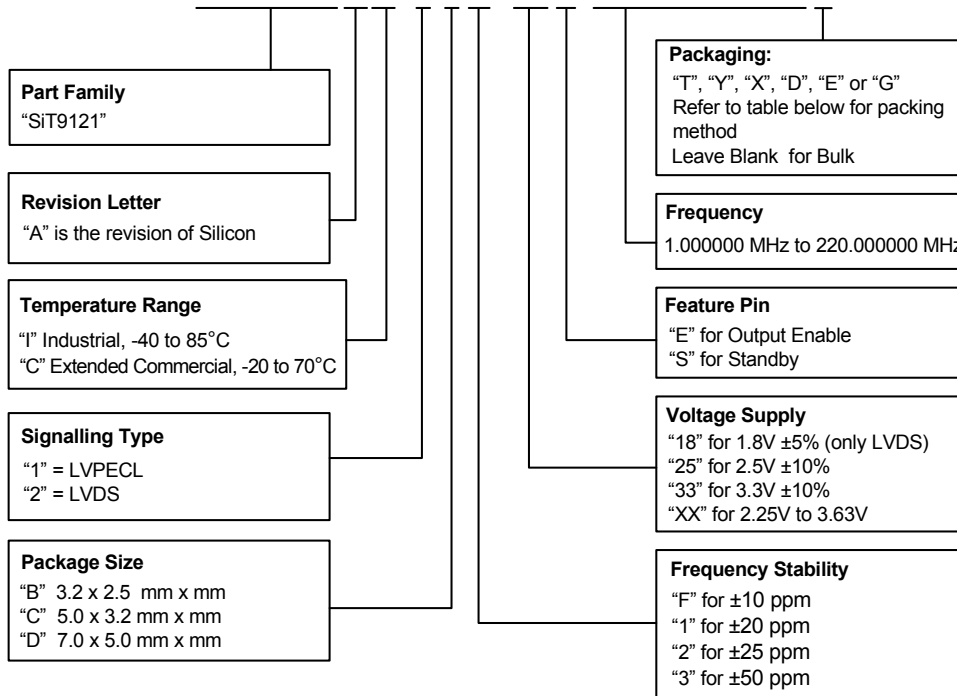
Package Size – Dimensions (Unit: mm) <sup>[1]</sup>	Recommended Land Pattern (Unit: mm) <sup>[2]</sup>
<p><b>3.2 x 2.5x 0.75 mm</b></p>  <p>Top view dimensions: 3.2±0.05 mm (width), 2.5±0.05 mm (height). Pin locations: #1, #2, #3 (bottom); #4, #5, #6 (top). Top marking: YXXXX. Bottom marking: 0.75±0.05 mm.</p> <p>Land pattern dimensions: 2.25 mm (width), 1.6 mm (height), 0.65 mm (pitch), 1.05 mm (pitch), 1.00 mm (height).</p>	 <p>Land pattern dimensions: 2.25 mm (width), 1.6 mm (height), 0.65 mm (pitch), 1.05 mm (pitch), 1.00 mm (height).</p>
<p><b>5.0 x 3.2 x 0.75 mm</b></p>  <p>Top view dimensions: 5.0±0.10 mm (width), 3.2±0.10 mm (height). Pin locations: #1, #2, #3 (bottom); #4, #5, #6 (top). Top marking: YXXXX. Bottom marking: 0.75±0.05 mm.</p> <p>Land pattern dimensions: 2.54 mm (width), 2.20 mm (height), 0.90 mm (pitch), 0.90 mm (pitch).</p>	 <p>Land pattern dimensions: 2.54 mm (width), 2.20 mm (height), 0.90 mm (pitch), 0.90 mm (pitch).</p>
<p><b>7.0 x 5.0x 0.90 mm</b></p>  <p>Top view dimensions: 7.0±0.10 mm (width), 5.0±0.10 mm (height). Pin locations: #1, #2, #3 (bottom); #4, #5, #6 (top). Top marking: YXXXX. Bottom marking: 0.90±0.10 mm.</p> <p>Land pattern dimensions: 5.08 mm (width), 3.80 mm (height), 1.60 mm (pitch), 1.60 mm (pitch).</p>	 <p>Land pattern dimensions: 5.08 mm (width), 3.80 mm (height), 1.60 mm (pitch), 1.60 mm (pitch).</p>

**Notes:**

1. Top Marking: Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.
2. A capacitor of value 0.1 μF between Vdd and GND is recommended.

**Ordering Information**

SiT9121AC-1C2-33E125.000000T



**Ordering Codes for Supported Tape & Reel Packing Method**

Device Size	8 mm T&R (3ku)	8 mm T&R (1ku)	8 mm T&R (250u)	12 mm T&R (3ku)	12 mm T&R (1ku)	12 mm T&R (250u)	16 mm T&R (3ku)	16 mm T&R (1ku)	16 mm T&R (250u)
7.0 x 5.0 mm	-	-	-	-	-	-	T	Y	X
5.0 x 3.2 mm	-	-	-	T	Y	X	-	-	-
3.2 x 2.5 mm	D	E	G	T	Y	X	-	-	-

**Frequencies Not Supported**

Range 1: From 209.000001 MHz to 210.999999 MHz

### Revision History

Version	Release Date	Change Summary
1.01	2/20/13	Original
1.02	12/3/13	Added input specifications, LVPECL/LVDS waveforms, packaging T&R options
1.03	2/6/14	Added 8mm T&R option and $\pm 10$ ppm
1.04	4/8/14	Included 1.8V option for LVDS output only
1.05	7/30/14	Included Thermal Consideration table
1.06	10/20/14	Modified Thermal Consideration values. Preliminary removed from the title

© SiTime Corporation 2014. The information contained herein is subject to change at any time without notice. SiTime assumes no responsibility or liability for any loss, damage or defect of a Product which is caused in whole or in part by (i) use of any circuitry other than circuitry embodied in a SiTime product, (ii) misuse or abuse including static discharge, neglect or accident, (iii) unauthorized modification or repairs which have been soldered or altered during assembly and are not capable of being tested by SiTime under its normal test conditions, or (iv) improper installation, storage, handling, warehousing or transportation, or (v) being subjected to unusual physical, thermal, or electrical stress.

**Disclaimer:** SiTime makes no warranty of any kind, express or implied, with regard to this material, and specifically disclaims any and all express or implied warranties, either in fact or by operation of law, statutory or otherwise, including the implied warranties of merchantability and fitness for use or a particular purpose, and any implied warranty arising from course of dealing or usage of trade, as well as any common-law duties relating to accuracy or lack of negligence, with respect to this material, any SiTime product and any product documentation. Products sold by SiTime are not suitable or intended to be used in a life support application or component, to operate nuclear facilities, or in other mission critical applications where human life may be involved or at stake. All sales are made conditioned upon compliance with the critical uses policy set forth below.

**CRITICAL USE EXCLUSION POLICY**  
BUYER AGREES NOT TO USE SITIME'S PRODUCTS FOR ANY APPLICATION OR IN ANY COMPONENTS USED IN LIFE SUPPORT DEVICES OR TO OPERATE NUCLEAR FACILITIES OR FOR USE IN OTHER MISSION-CRITICAL APPLICATIONS OR COMPONENTS WHERE HUMAN LIFE OR PROPERTY MAY BE AT STAKE.

SiTime owns all rights, title and interest to the intellectual property related to SiTime's products, including any software, firmware, copyright, patent, or trademark. The sale of SiTime products does not convey or imply any license under patent or other rights. SiTime retains the copyright and trademark rights in all documents, catalogs and plans supplied pursuant to or ancillary to the sale of products or services by SiTime. Unless otherwise agreed to in writing by SiTime, any reproduction, modification, translation, compilation, or representation of this material shall be strictly prohibited.



# Supplemental Information

The Supplemental Information section is not part of the datasheet and is for informational purposes only.

# Silicon MEMS Outperforms Quartz

## Best Reliability

Silicon is inherently more reliable than quartz. Unlike quartz suppliers, SiTime has in-house MEMS and analog CMOS expertise, which allows SiTime to develop the most reliable products. Figure 1 shows a comparison with quartz technology.

### Why is SiTime Best in Class:

- SiTime’s MEMS resonators are vacuum sealed using an advanced EpiSeal™ process, which eliminates foreign particles and improves long term aging and reliability
- World-class MEMS and CMOS design expertise

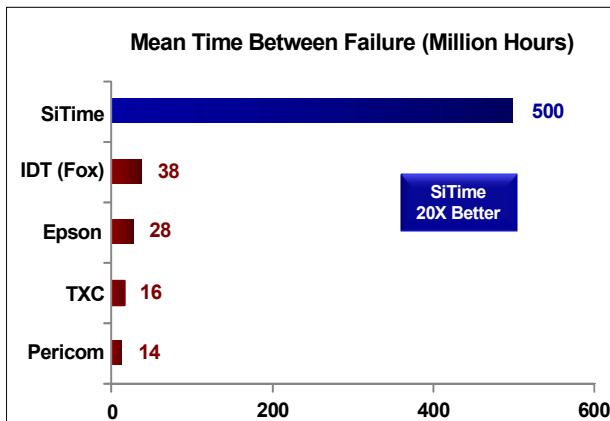


Figure 1. Reliability Comparison<sup>[1]</sup>

## Best Aging

Unlike quartz, MEMS oscillators have excellent long term aging performance which is why every new SiTime product specifies 10-year aging. A comparison is shown in Figure 2.

### Why is SiTime Best in Class:

- SiTime’s MEMS resonators are vacuum sealed using an advanced EpiSeal process, which eliminates foreign particles and improves long term aging and reliability
- Inherently better immunity of electrostatically driven MEMS resonator

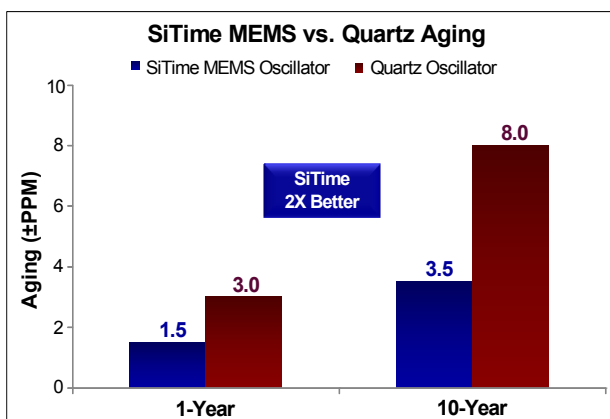


Figure 2. Aging Comparison<sup>[2]</sup>

## Best Electro Magnetic Susceptibility (EMS)

SiTime’s oscillators in plastic packages are up to 54 times more immune to external electromagnetic fields than quartz oscillators as shown in Figure 3.

### Why is SiTime Best in Class:

- Internal differential architecture for best common mode noise rejection
- Electrostatically driven MEMS resonator is more immune to EMS

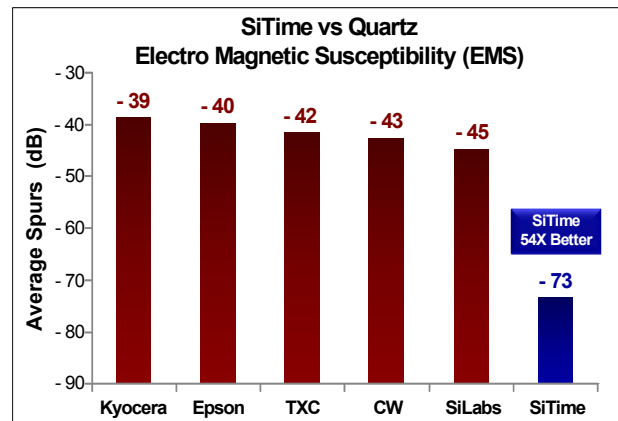


Figure 3. Electro Magnetic Susceptibility (EMS)<sup>[3]</sup>

## Best Power Supply Noise Rejection

SiTime’s MEMS oscillators are more resilient against noise on the power supply. A comparison is shown in Figure 4.

### Why is SiTime Best in Class:

- On-chip regulators and internal differential architecture for common mode noise rejection
- Best analog CMOS design expertise

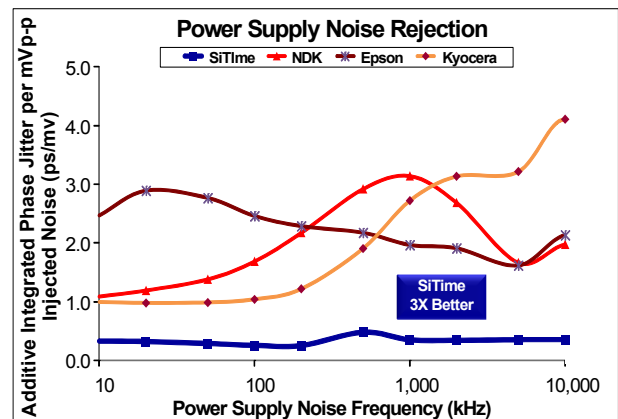


Figure 4. Power Supply Noise Rejection<sup>[4]</sup>

## Best Vibration Robustness

High-vibration environments are all around us. All electronics, from handheld devices to enterprise servers and storage systems are subject to vibration. Figure 5 shows a comparison of vibration robustness.

### Why is SiTime Best in Class:

- The moving mass of SiTime’s MEMS resonators is up to 3000 times smaller than quartz
- Center-anchored MEMS resonator is the most robust design

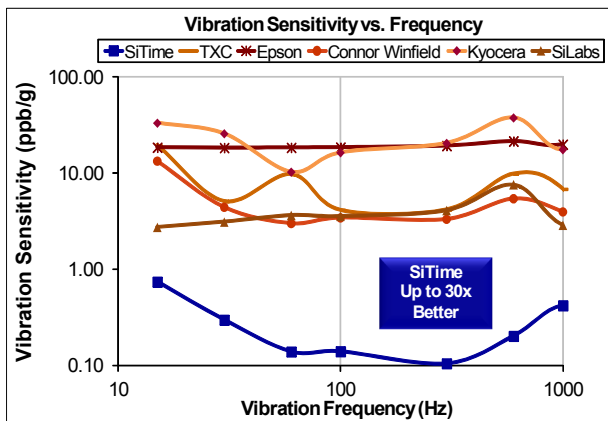


Figure 5. Vibration Robustness<sup>[5]</sup>

## Best Shock Robustness

SiTime’s oscillators can withstand at least 50,000 g shock. They all maintain their electrical performance in operation during shock events. A comparison with quartz devices is shown in Figure 6.

### Why is SiTime Best in Class:

- The moving mass of SiTime’s MEMS resonators is up to 3000 times smaller than quartz
- Center-anchored MEMS resonator is the most robust design

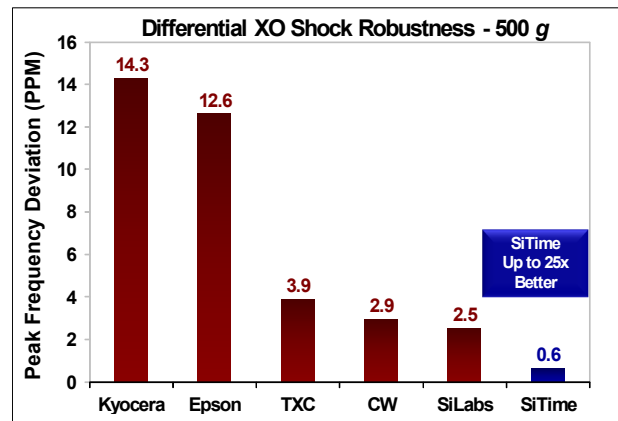


Figure 6. Shock Robustness<sup>[6]</sup>

### Notes:

1. Data Source: Reliability documents of named companies.
2. Data source: SiTime and quartz oscillator devices datasheets.
3. Test conditions for Electro Magnetic Susceptibility (EMS):
  - According to IEC EN61000-4.3 (Electromagnetic compatibility standard)
  - Field strength: 3V/m
  - Radiated signal modulation: AM 1 kHz at 80% depth
  - Carrier frequency scan: 80 MHz – 1 GHz in 1% steps
  - Antenna polarization: Vertical
  - DUT position: Center aligned to antenna

**Devices used in this test:**  
 SiTime, SiT9120AC-1D2-33E156.250000 - MEMS based - 156.25 MHz  
 Epson, EG-2102CA 156.2500M-PHPAL3 - SAW based - 156.25 MHz  
 TXC, BB-156.250MBE-T - 3rd Overtone quartz based - 156.25 MHz  
 Kyocera, KC7050T156.250P30E00 - SAW based - 156.25 MHz  
 Connor Winfield (CW), P123-156.25M - 3rd overtone quartz based - 156.25 MHz  
 SiLabs, Si590AB-BDG - 3rd overtone quartz based - 156.25 MHz
4. 50 mV pk-pk Sinusoidal voltage.
 

**Devices used in this test:**  
 SiTime, SiT8208AI-33-33E-25.000000, MEMS based - 25 MHz  
 NDK, NZ2523SB-25.6M - quartz based - 25.6 MHz  
 Kyocera, KC2016B25MOC1GE00 - quartz based - 25 MHz  
 Epson, SG-310SCF-25M0-MB3 - quartz based - 25 MHz
5. **Devices used in this test:** same as EMS test stated in Note 3.
6. Test conditions for shock test:
  - MIL-STD-883F Method 2002
  - Condition A: half sine wave shock pulse, 500-g, 1ms
  - Continuous frequency measurement in 100 μs gate time for 10 seconds

**Devices used in this test:** same as EMS test stated in Note 3
7. Additional data, including setup and detailed results, is available upon request to qualified customers. Please contact [productsupport@sitime.com](mailto:productsupport@sitime.com).

# Document Feedback Form



The Smart Timing Choice™

SiTime values your input in improving our documentation. Click [here](#) for our online feedback form or fill out and email the form below to [productsupport@sitime.com](mailto:productsupport@sitime.com).

1. Does the Electrical Characteristics table provide complete information? Yes No

If No, what parameters are missing?

---

2. Is the organization of this document easy to follow? Yes No

If "No," please suggest improvements that we can make:

---

3. Is there any application specific information that you would like to see in this document? (Check all that apply)

EMI Termination recommendations Shock and vibration performance Other

If "Other," please specify:

---

4. Are there any errors in this document? Yes No

If "Yes", please specify (what and where):

---

5. Do you have additional recommendations for this document?

---

Name \_\_\_\_\_

Title \_\_\_\_\_

Company \_\_\_\_\_

Address \_\_\_\_\_

City / State or Province / Postal Code / Country \_\_\_\_\_

Telephone \_\_\_\_\_

Application \_\_\_\_\_

Would you like a reply? Yes No

Thank you for your feedback. Please click the email icon in your Adobe Reader tool bar and send to [productsupport@sitime.com](mailto:productsupport@sitime.com). Or you may use our [online feedback form](#).

# Document Feedback Form



SiTime values your input in improving our documentation. Click [here](#) for our online feedback form or fill out and email the form below to [productsupport@sitime.com](mailto:productsupport@sitime.com).

1. Does the Electrical Characteristics table provide complete information? Yes      No

If No, what parameters are missing?

---

2. Is the organization of this document easy to follow? Yes      No

If "No," please suggest improvements that we can make:

---

3. Is there any application specific information that you would like to see in this document? (Check all that apply)

EMI                      Termination recommendations                      Shock and vibration performance                      Other

If "Other," please specify:

---

4. Are there any errors in this document? Yes      No

If "Yes", please specify (what and where):

---

5. Do you have additional recommendations for this document?

---

Name \_\_\_\_\_

Title \_\_\_\_\_

Company \_\_\_\_\_

Address \_\_\_\_\_

City / State or Province / Postal Code / Country \_\_\_\_\_

Telephone \_\_\_\_\_

Application \_\_\_\_\_

Would you like a reply? Yes      No

Thank you for your feedback. Please click the email icon in your Adobe Reader tool bar and send to [productsupport@sitime.com](mailto:productsupport@sitime.com). Or you may use our [online feedback form](#).



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

**Телефон:** 8 (812) 309 58 32 (многоканальный)

**Факс:** 8 (812) 320-02-42

**Электронная почта:** [org@eplast1.ru](mailto:org@eplast1.ru)

**Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.